



#### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

## Product Summary (Typ. @ V<sub>GS</sub> = -4.5V, T<sub>A</sub> = +25°C)

V <sub>DSS</sub>	R <sub>DS(on)</sub>	Qg	$Q_{gd}$	Ι <sub>D</sub>
-20V	80mΩ	3.3nC	0.6nC	-4A

#### **Description**

This new generation MOSFET is designed to minimize the on-state resistance  $(R_{D1D2(ON)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

### **Applications**

- Battery Management
- Load Switch
- Battery Protection

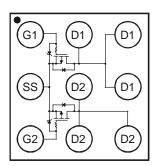


## **Features and Benefits**

- LD-MOS Technology with the Lowest Figure of Merit:  $R_{DS(on)} = 80 m\Omega \text{ to Minimize On-State Losses} \\ Q_{\alpha} = 3.3 nC \text{ for Ultra-Fast Switching}$
- $V_{gs(th)} = -0.7V$  typ. for a Low Turn-On Potential
- CSP with Footprint 1.5mm x 1.5mm
- Height = 0.62mm for Low Profile
- ESD = 3kV HBM Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: U-WLB1515-9
- Terminal Connections: See Diagram Below
- Weight: 0.0018 grams (Approximate)



Top View

#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP2100UCB9-7	U-WLB1515-9	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

U-WLB1515-9

● 6W YM

6W = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

#### Date Code Key

Year	2012	2	2013		2014	20	15	2016		2017	2	2018
Code	Z		Α		В	(		D		Е		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		$V_{D1D2}$	-20	V	
Gate-Source Voltage		V <sub>GS</sub>	-6	V	
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	I <sub>D1D2</sub>	-3.0 -2.1	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	I <sub>D1D2</sub>	-4.0 -3.0	A
Continuous Source Pin Current (Note 6)		Is	-2.0	Α	
Continuous Gate Clamp Current (Note 6)		I <sub>G</sub>	-0.4	Α	
Pulsed Source Pin Current (Pulse duration 10µs, d	uty cycle ≤	I <sub>SM</sub>	-15	Α	
Pulsed Drain Current (Pulse duration 10µs, duty cy	rcle ≤ 1%)	I <sub>DM</sub>	-28	Α	
Pulsed Gate Clamp Current (Pulse duration 10µs,	duty cycle :	≤ 1%)	I <sub>GM</sub>	-6	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	P <sub>D</sub>	0.8	W
Total Power Dissipation (Note 6)	P <sub>D</sub>	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	152	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0</sub> JA	65	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

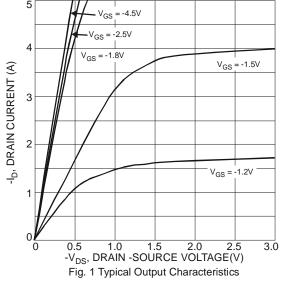
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>D1D2</sub>	-20	-	_	V	$V_{GS} = 0V$ , $I_{D1D2} = -250\mu A$
Gate-Source Breakdown Voltage	BV <sub>GSS</sub>	-6.1	-	_	V	$I_{GS} = -250\mu A, V_{D1D2} = 0V$
Zero Gate Voltage Drain Current @T <sub>C</sub> = +25°C	I <sub>DDS</sub>	_	-	-1	μA	$V_{D1D2} = -16V, V_{GS} = 0V$
Gate-Source Leakage	$I_{GSS}$	_	_	-100	nA	$V_{GS} = -6V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.4	-0.7	-0.9	V	$V_{D1D2} = V_{GS}, I_{DS} = -250\mu A$
		_	80	100		V <sub>GS</sub> = -4.5V, I <sub>D1D2</sub> =- 1A
Static Drain-Source On-Resistance	R <sub>D1D2(ON)</sub>	_	105	130	mΩ	$V_{GS} = -2.5V$ , $I_{D1D2} = -1A$
		_	140	175		$V_{GS} = -1.8V, I_{D1D2} = -1A$
Forward Transfer Admittance	Y <sub>fs</sub>	_	5.3	_	S	V <sub>D1D2</sub> = -10V, I <sub>D1D2</sub> = -1A
DIODE CHARACTERISTICS						
Diode Forward Voltage (Note 6)	$V_{SD}$	_	-0.7	-1	V	$V_{GS} = 0V, I_{D1D2} = -1A$
Reverse Recovery Charge	Qrr	_	18	_	nC	$V_{dd} = -9.5V, I_F = -1A,$
Reverse Recovery Time	t <sub>rr</sub>	_	34	_	ns	di/dt = 200A/µs
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>	_	232	310	pF	101/1/
Output Capacitance	Coss	_	107	150	pF	$V_{D1D2} = -10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	43.5	55	pF	1 = 1.0Wii 12
Total Gate Charge (4.5V)	Qg	_	3.3	4.2	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	0.3	_	nC	$V_{GS} = -4.5V, V_{D1D2} = -10V,$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.6	_	nC	I <sub>D1D2</sub> = -1A
Gate Charge at V <sub>th</sub>	Q <sub>g(th)</sub>	_	0.2	_	nC	
Turn-On Delay Time	t <sub>D(on)</sub>	_	8.5	_	ns	
Turn-On Rise Time	t <sub>r</sub>	_	7.0	_	ns	$V_{D1D2} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t <sub>D(off)</sub>	_	47	_	ns	$I_{D1D2} = -1A, R_G = 30\Omega,$
Turn-Off Fall Time	t <sub>f</sub>	_	28	_	ns	

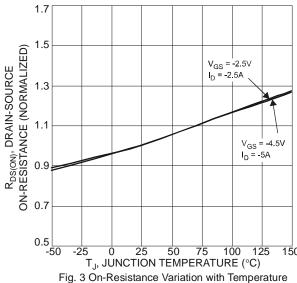
Notes:

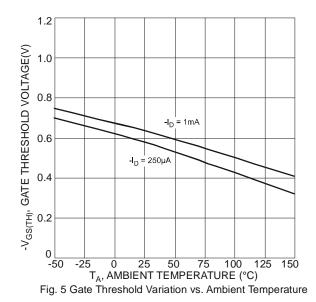
- Device mounted on FR-4 PCB with minimum recommended pad layout.
   Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

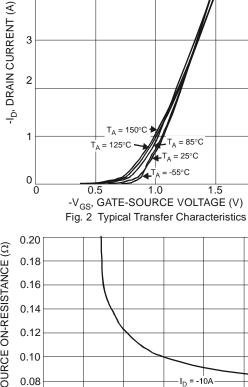
2.0



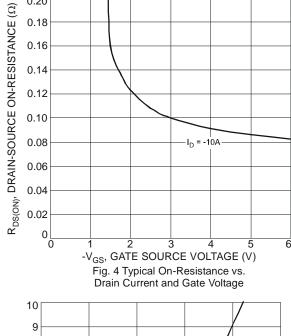








5



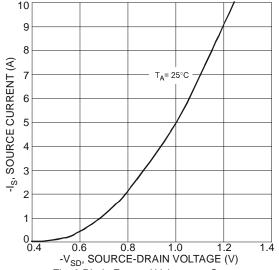
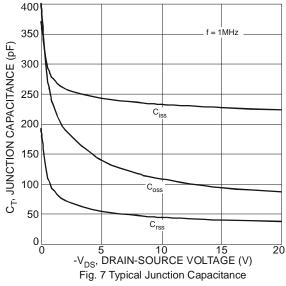
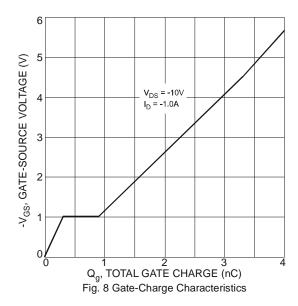
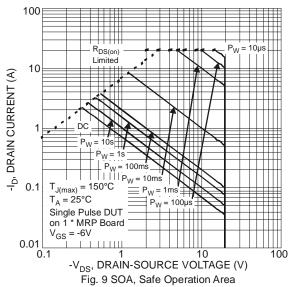


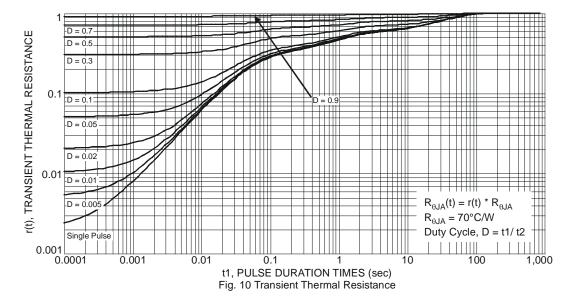
Fig. 6 Diode Forward Voltage vs. Current







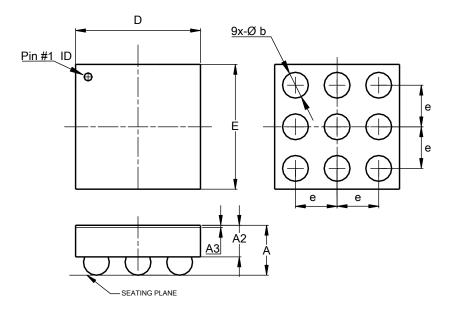






# **Package Outline Dimensions**

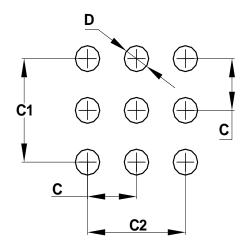
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-WLB1515-9						
Dim	Min	Max	Тур			
Α		0.62				
A2		0.36	0.36			
A3	0.020	0.030	0.025			
b	0.27	0.37	0.32			
D	1.47	1.50	1.49			
Е	1.47	1.50	1.49			
е			0.50			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.50			
C1	1.00			
C2	1.00			
D	0.25			



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